

B-3 SiC•Diamond•Other Related Materials

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Poster Session March 27 (Fri.) 16:45 ~ 18:00

16:45 B3-P-01 **Multi Graphene Grown by Irradiated Graphite on Printing Paper by Femtosecond Laser**

¹Satoru Kaneko, ¹Yoshitada Shimizu, ¹Takeshi Rachi, ¹Chihiro Kato, ¹Satomi Tanaka, ²Toru Katakura, ³Hirifumi Takikawa, ⁴Akifumi Matsuda, ⁴Mamoru Yoshimoto

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16:45 B3-P-02 **Effects of Sputtering Power of Schottky Metal Layers on Rectifying Performance of Mo-SiC Schottky Contacts**

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